



ASICs for FAIR

FAIR UK Community Meeting – Daresbury Laboratory

Marcus French

26th January 2006

- Who we are
- Example technologies
 - Particle physics
 - Space Science
- ASIC Goup
 - Current Nuclear Structure physics activity
 - Ideas for Nustar
 - Details for Aida
 - Other experiments – EXL and R3B
- DAQ Systems
 - Current activity and trends
- Summary

Mission:

...to promote and support high-quality scientific and engineering research by developing and providing facilities and technical expertise in support of basic strategic and applied research programmes...

Chilbolton Observatory - 10



Daresbury Laboratory - 500



Rutherford Appleton Laboratory – 1200 staff



ISIS - The World's most intense pulsed source of neutrons

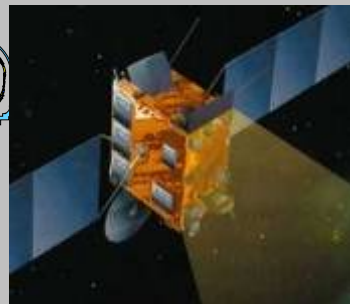
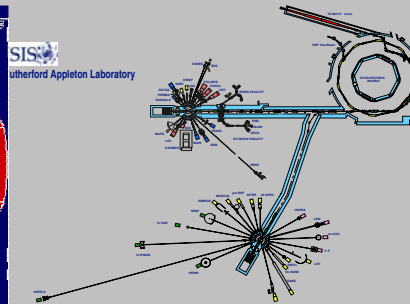
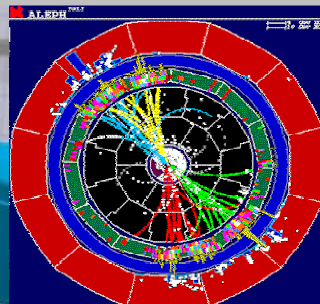
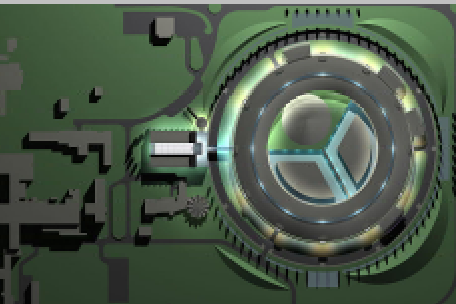
SRS - The World's first 2nd generation synchrotron source

CLF - The World's highest irradiance laser

CERN LHC - The World's highest data-rate detector

Space - Largest European department with >150 orbiting instruments.

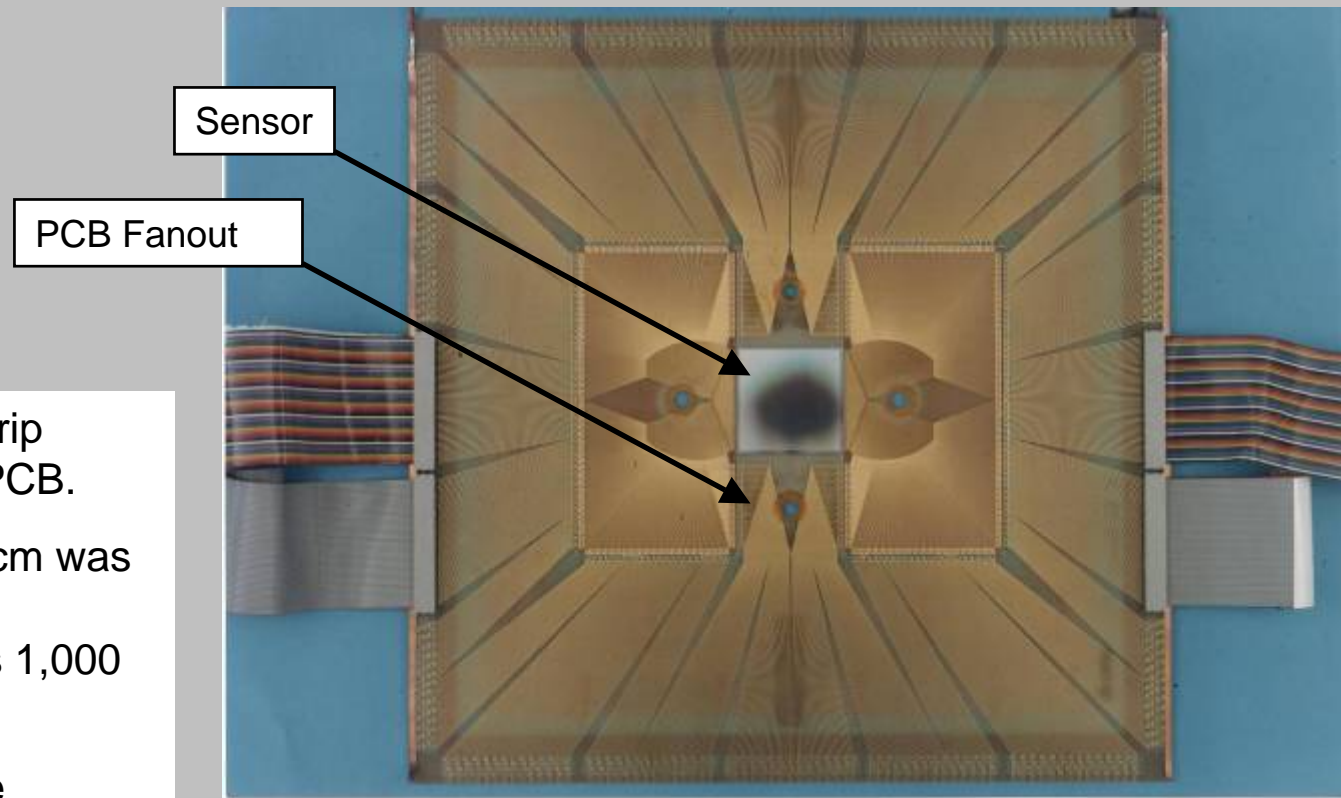
CMF – Micro-Nano facility



- Particle Physics:
 - Sensor Instrumentation
 - Microelectronics
 - DAQ Systems
- Space Science:
 - Instrument Systems
 - CMOS Sensors
 - Data conversion
- Future Trends



Early Microstrip Sensors

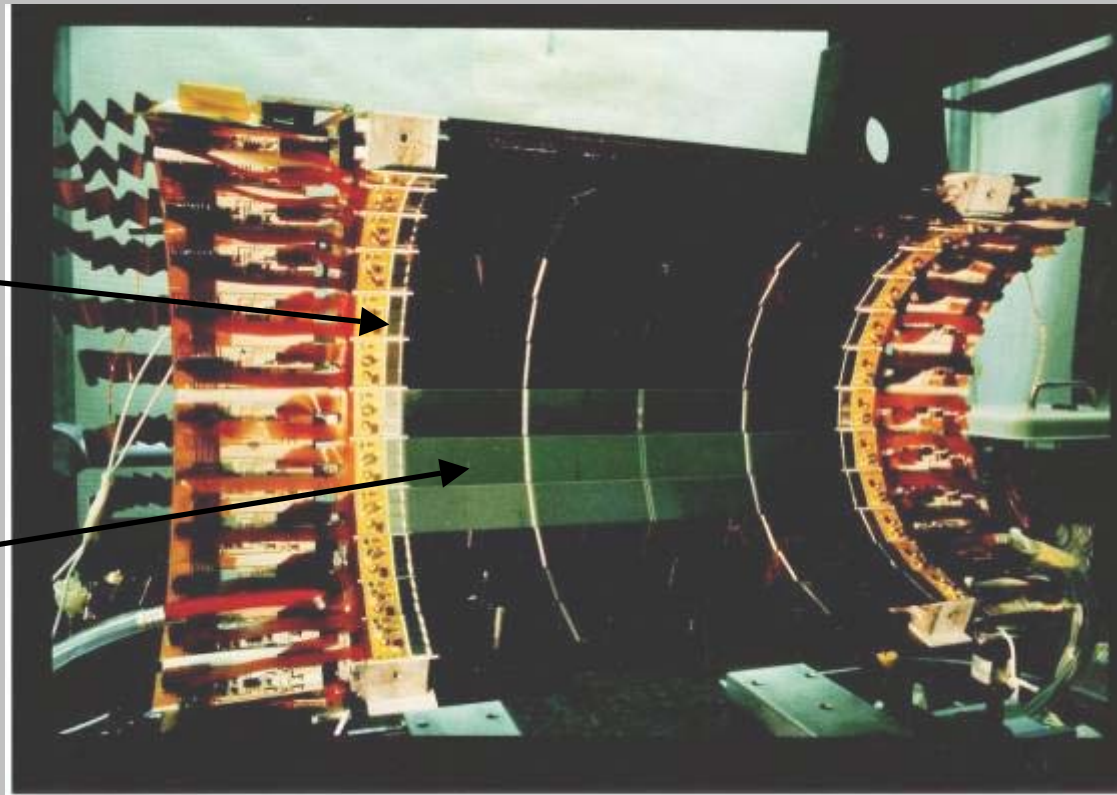


An example of a microstrip detector mounted on a PCB.

The detector, of 5cm x5cm was built for the CERN NA14 experiment and contains 1,000 strips at 50um pitch.

Ten such detectors were assembled at Imperial College to observe charmed particle physics decays.

Delphi Micro Vertex Detector



Early Microplex
ASICs

Silicon Detectors

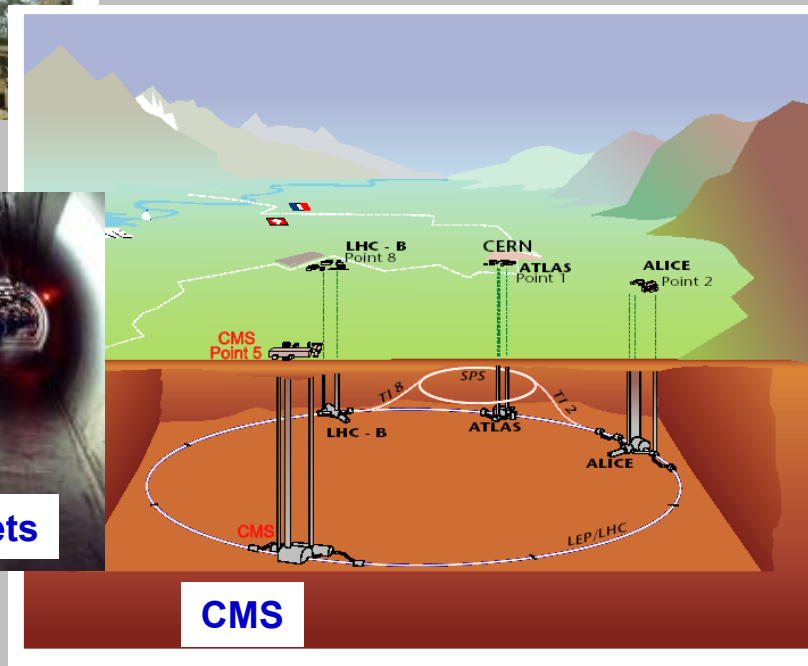
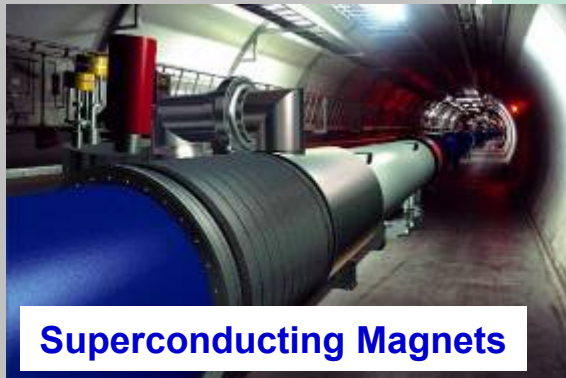
Today's Experiment: CMS



Large Hadron Collider Facility
Particle Accelerator

Tunnel 27 km

100 m underground

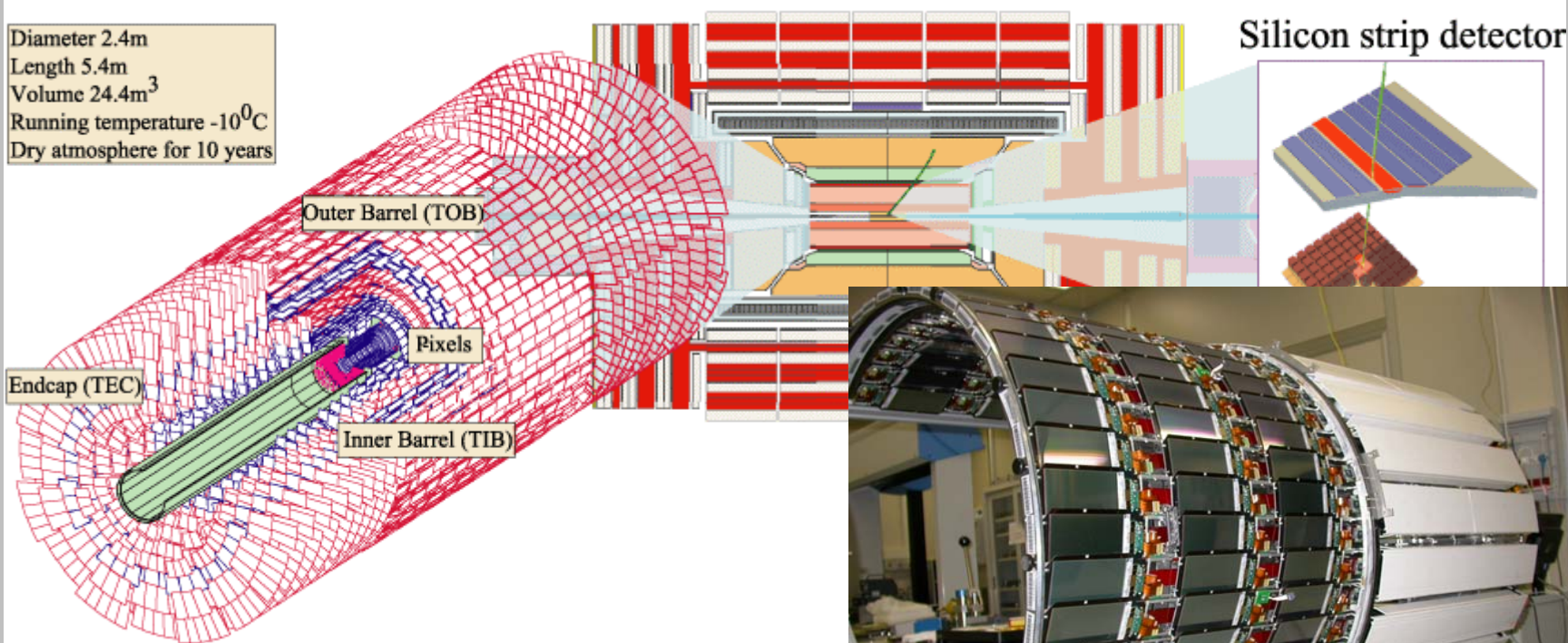


Long term project
Starts Operation 2007

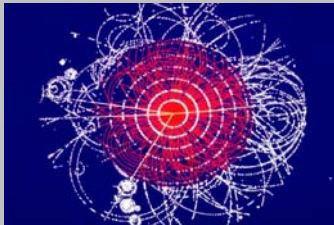
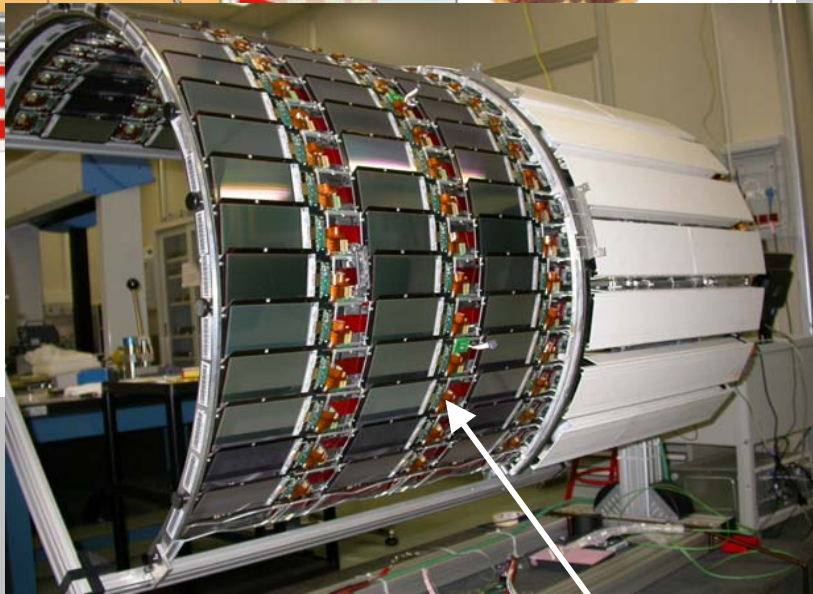
Counter rotating Proton beams ; bunch collision rate = 40 MHz ;

CMS Construction

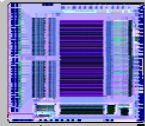
Diameter 2.4m
 Length 5.4m
 Volume 24.4m³
 Running temperature -10⁰C
 Dry atmosphere for 10 years



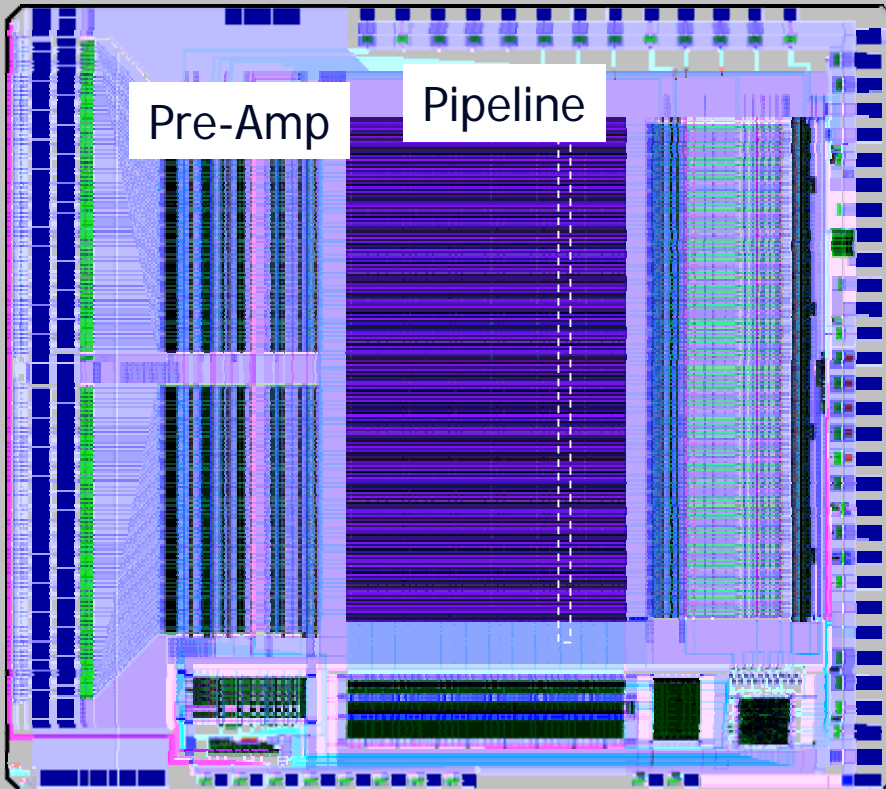
220 m² of silicon sensors
> 9 million silicon strips



Charged Track reconstruction.
Very high Granularity.



Front End Electronics



APV25 ASIC MEDG Design

Analogue **PIPELINE** clocked @ 40 MHz

On Detector v High Radiation

Low Power ; Low Noise

0.25 IBM deep sub-micron process

Each chip handles 128 strips

Holds each 25 nsec sample till Trigger slice

Serial output of all 128 strips at 100 kHz

Total > 70,000 chips => > 9 million strips @ 100 kHz

Technology 2: Data Acquisition

96 optical fibres
inputs, each a
Multiplexed pair of
APVs

25,000 strips

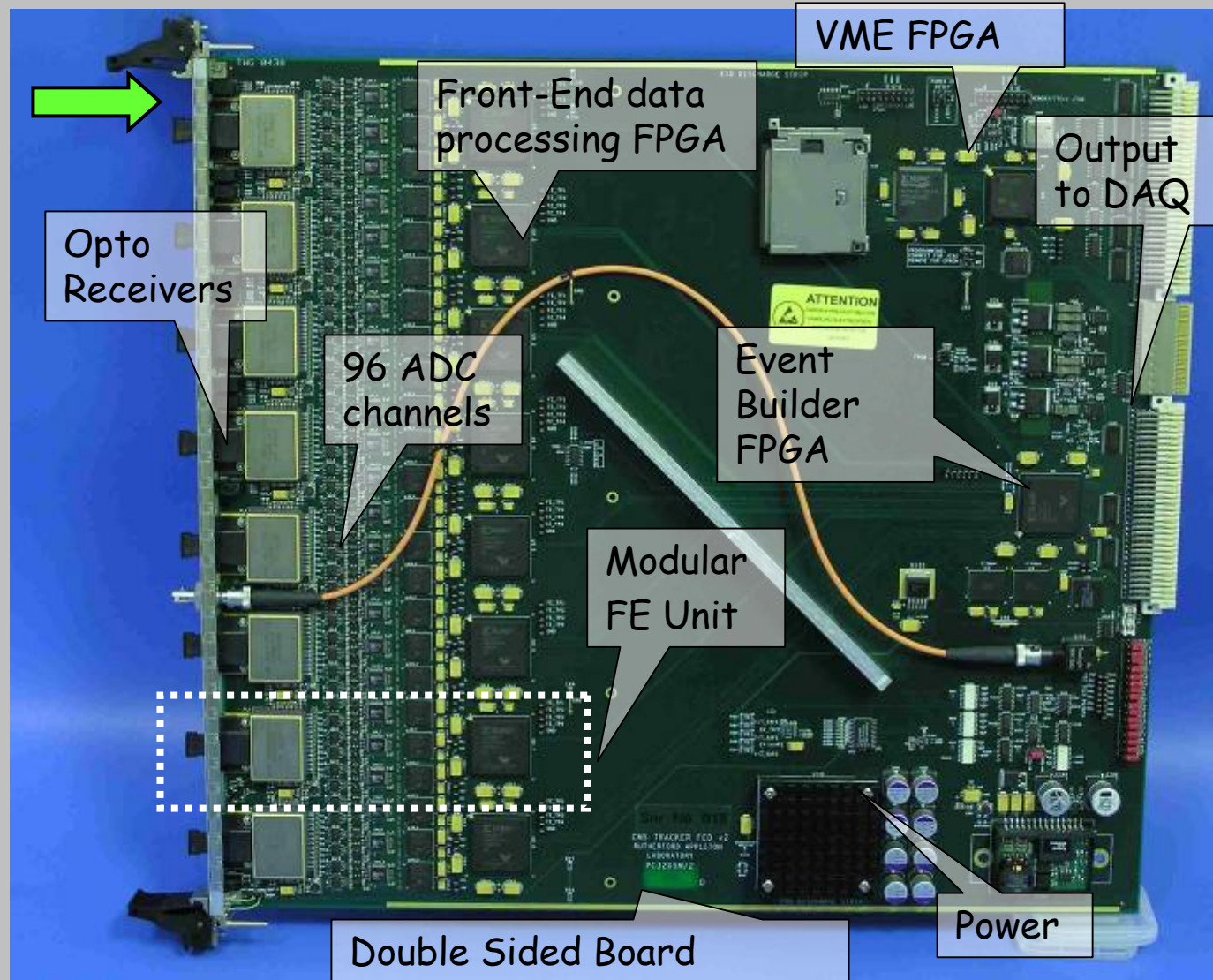
8 front end blocks
each driven by a 12
way optical ribbon
cable

Raw input data rate
= 3.4 GB/s.

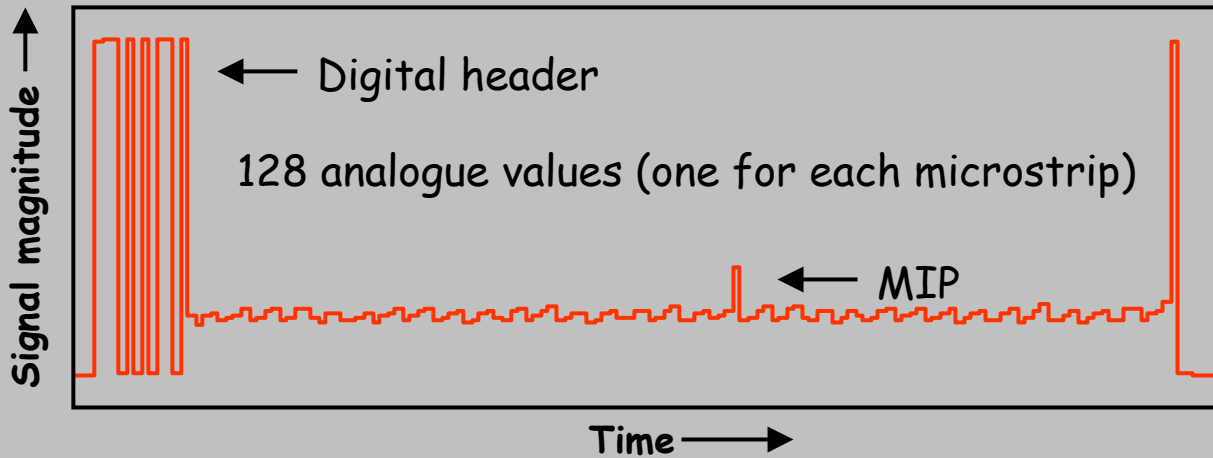
Extract hit strips

Processed Output
rate

< 200 MB/s



CMS DAQ Processing



To extract hit need to perform:

- Common mode subtraction
- Pedestal subtraction
- Cluster finding
- Sync checking

Opto-to-electrical conversion



Digitise & sync data



Find hit clusters

Optical ribbon cable input

Opto-RX, 12 way

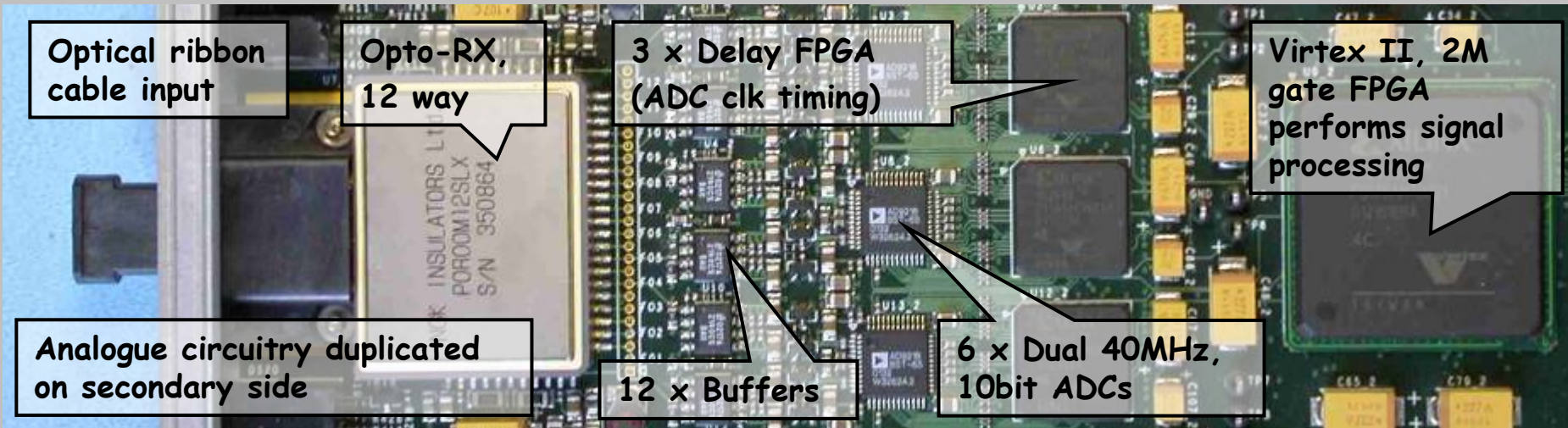
3 x Delay FPGA (ADC clk timing)

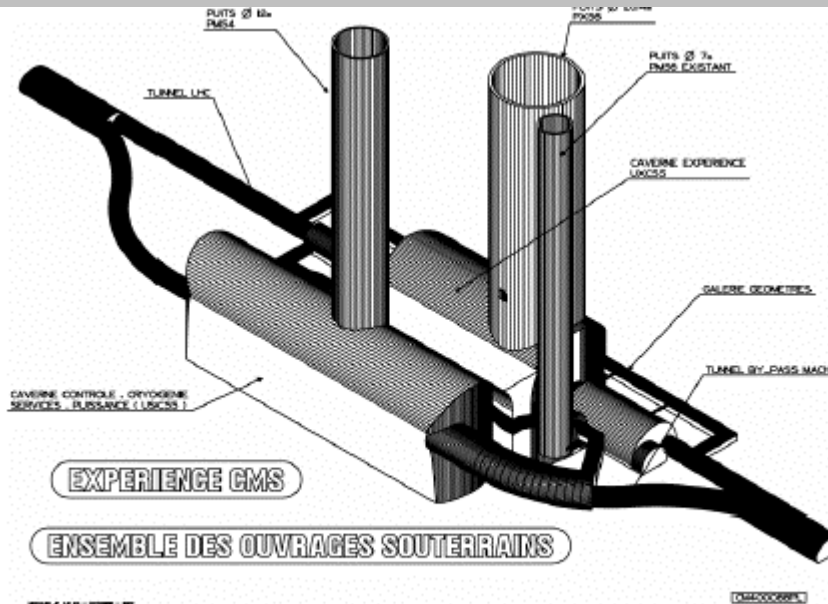
Virtex II, 2M gate FPGA performs signal processing

Analogue circuitry duplicated on secondary side

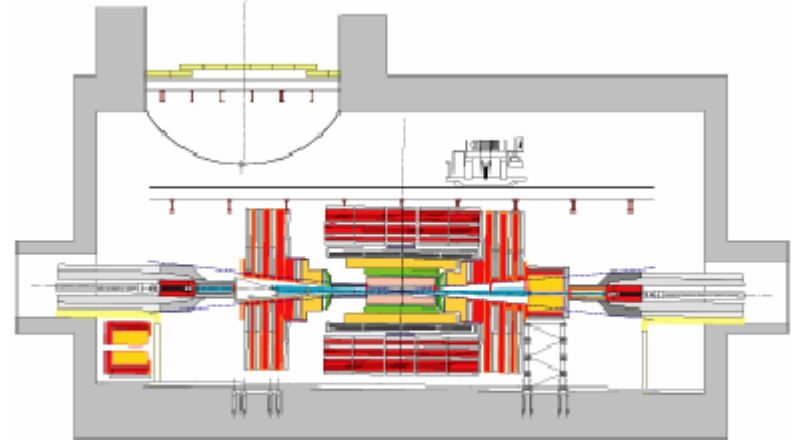
12 x Buffers

6 x Dual 40MHz, 10bit ADCs

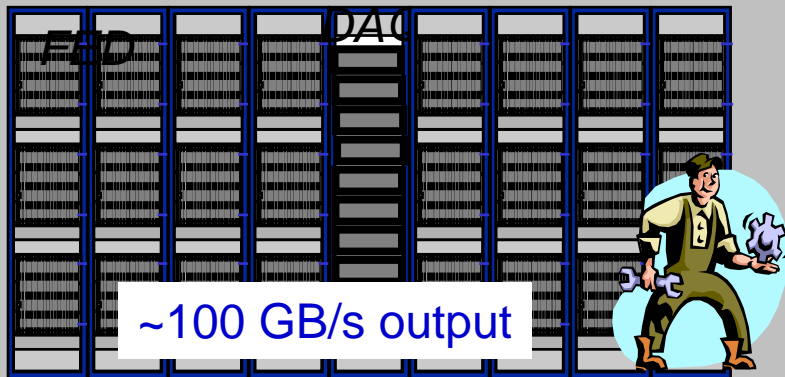




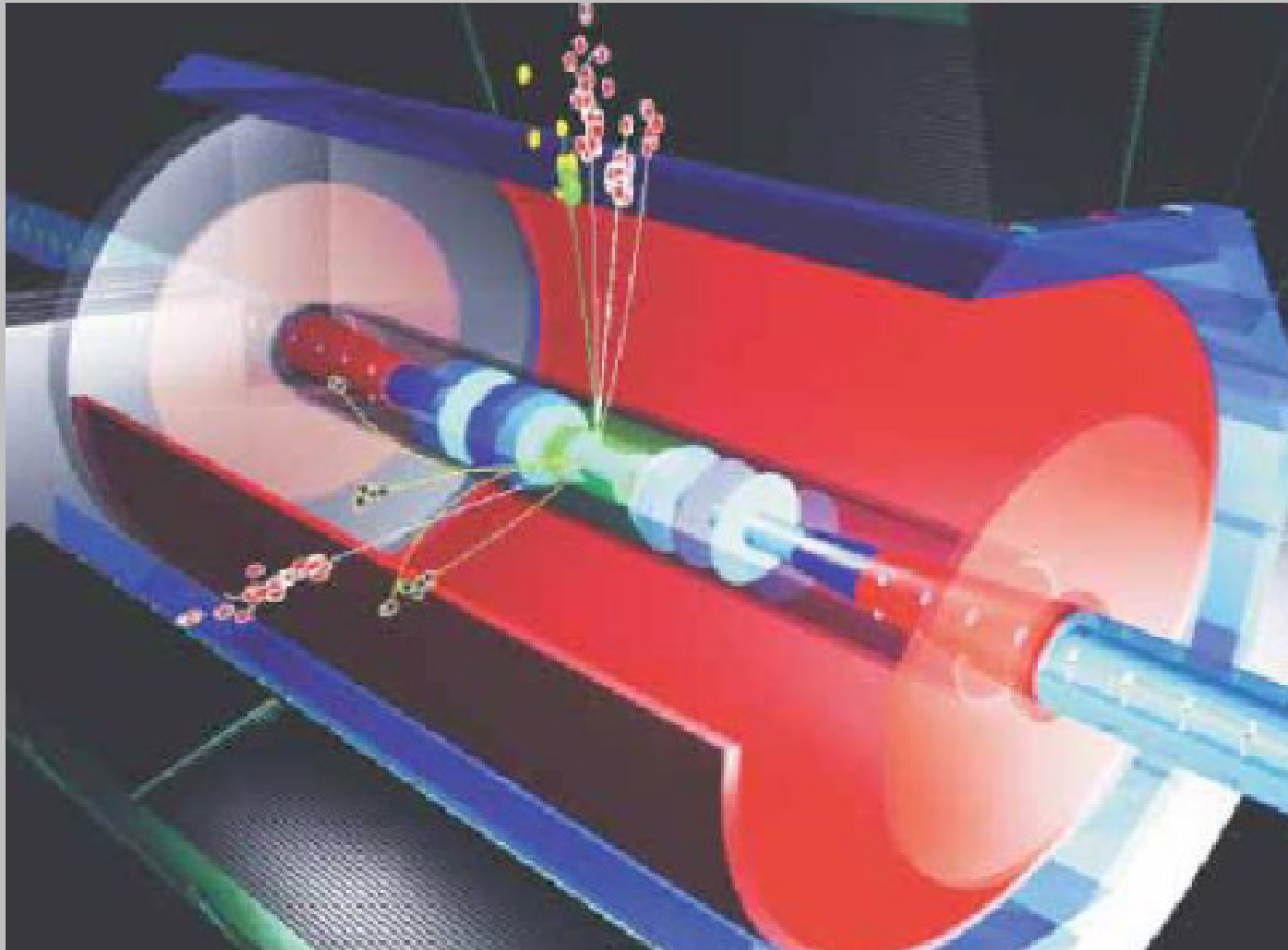
The underground area at point 5, showing the access shafts, the two large caverns and the wall between them



The CMS detector being assembled in UXC55



For 450 FEDs
 30 VME crates
 12 Racks electronics
 Installation in Q2->Q3 / 2006

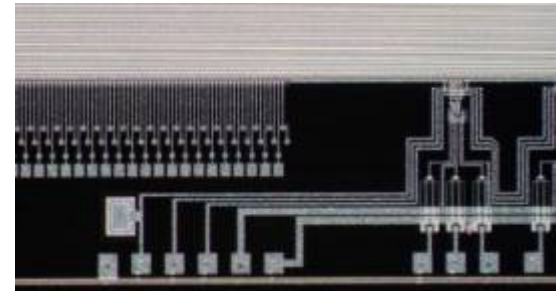


- Column parallel charge coupled device.
- First of these, CPCCD1, manufactured by e2v.

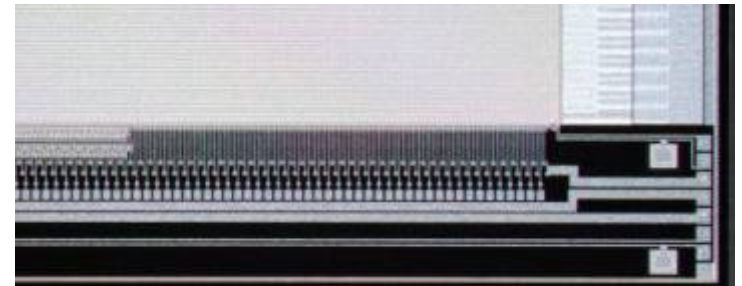


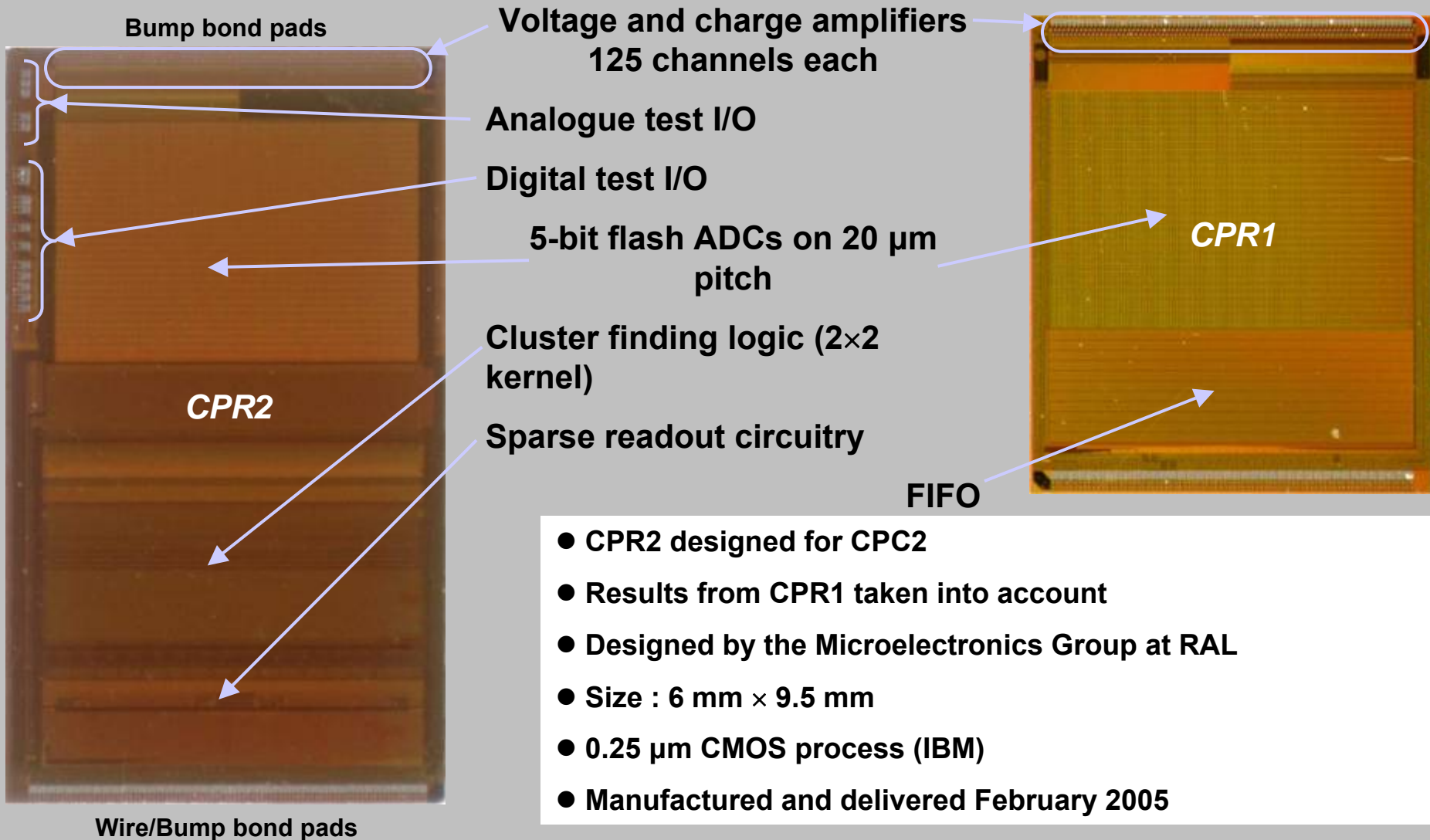
- Two phase, 400 (V) × 750 (H) pixels of size $20 \times 20 \mu\text{m}^2$.
- Metal strapping of clock gates.
- Two different gate shapes.
- Two different implant levels.

- Wire/bump bond connections to readout chip and external electronics.
 - Direct connections and 2-stage source followers:

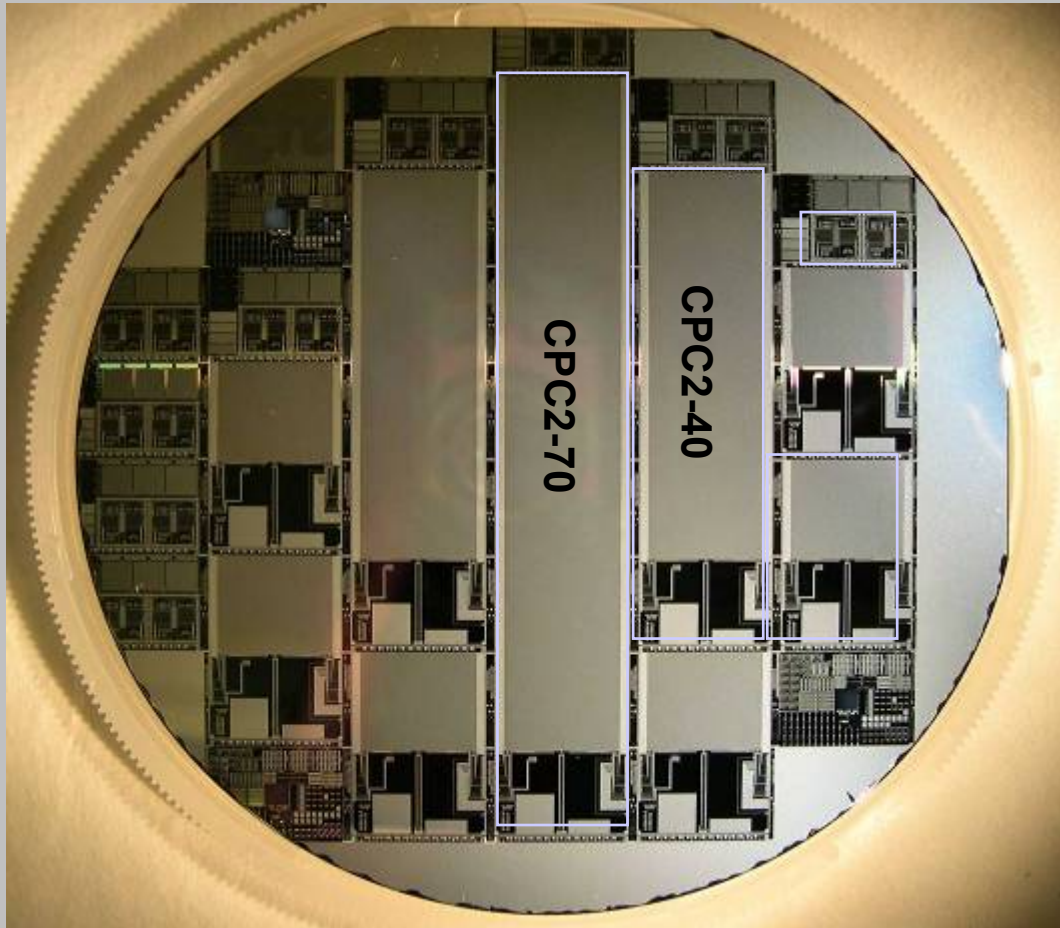


- Direct connections and single stage source followers ($20 \mu\text{m}$ pitch):



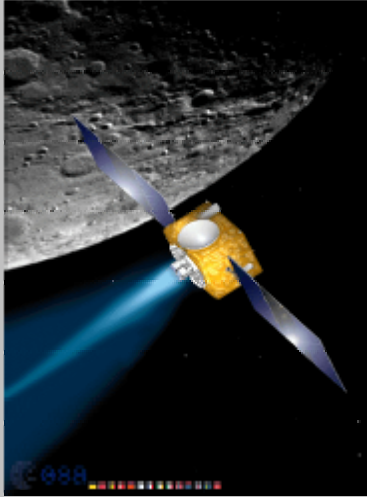


- CPR2 designed for CPC2
- Results from CPR1 taken into account
- Designed by the Microelectronics Group at RAL
- Size : 6 mm \times 9.5 mm
- 0.25 μm CMOS process (IBM)
- Manufactured and delivered February 2005



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 - CMOS Sensors
 - Data conversion
- Future Trends

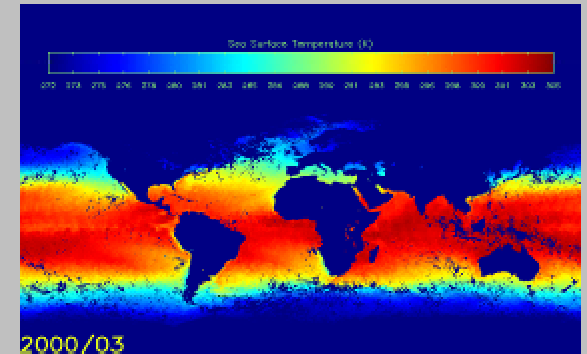




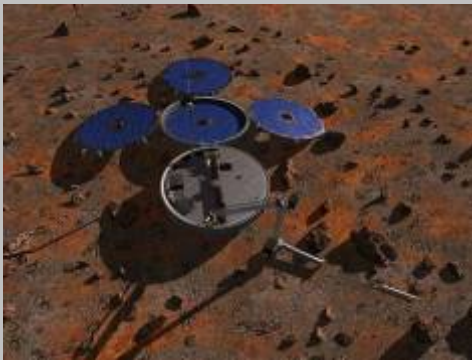
MOON



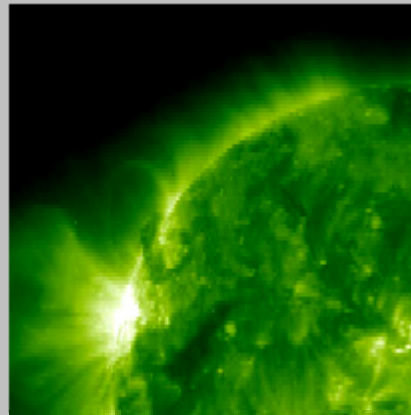
LAND



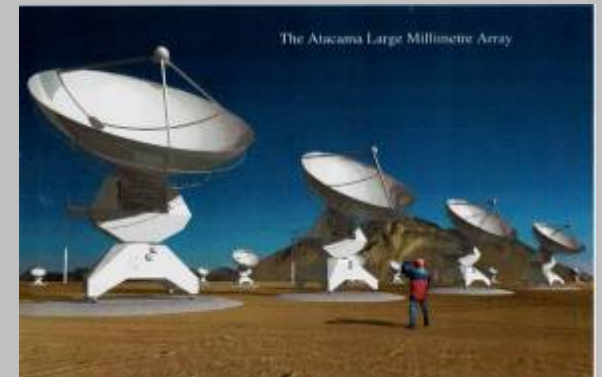
SEA



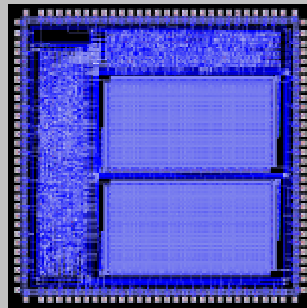
PLANETS



SUN



GALAXIES



ASIC: 0.8um DMILL process

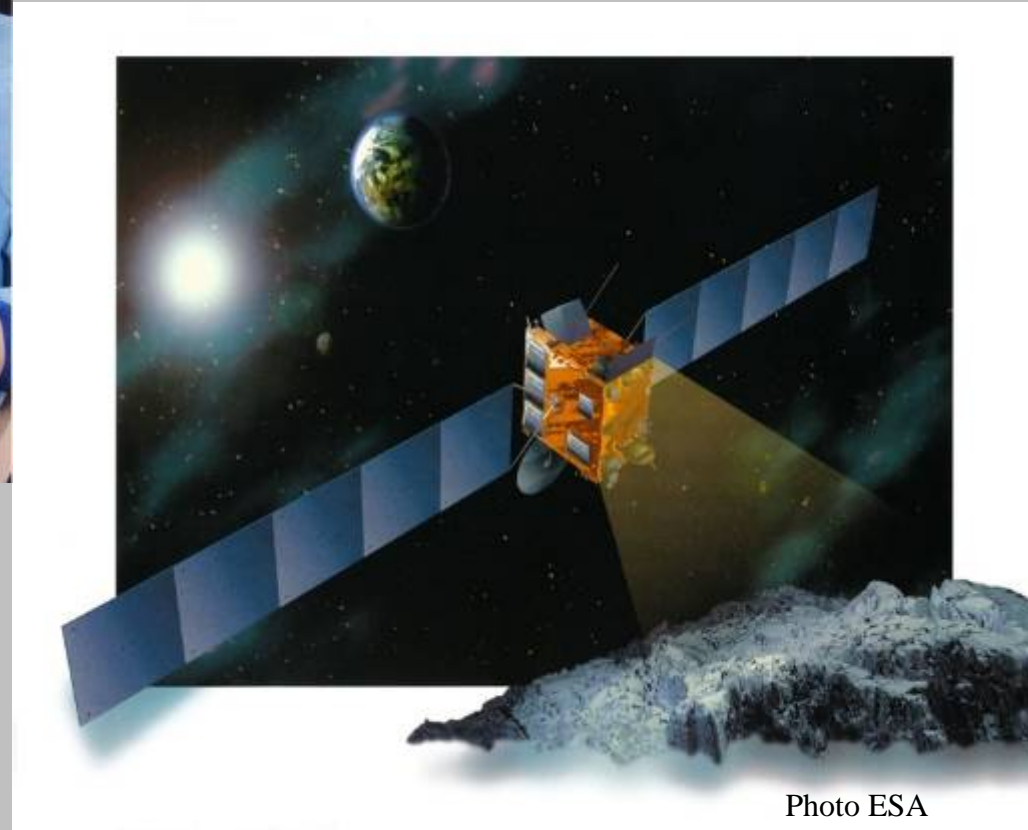
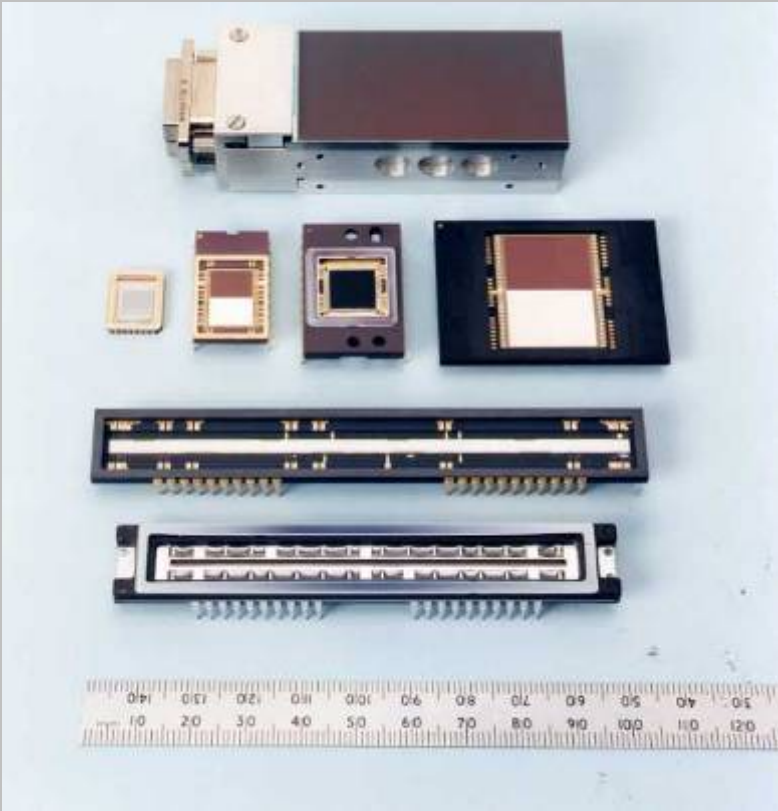
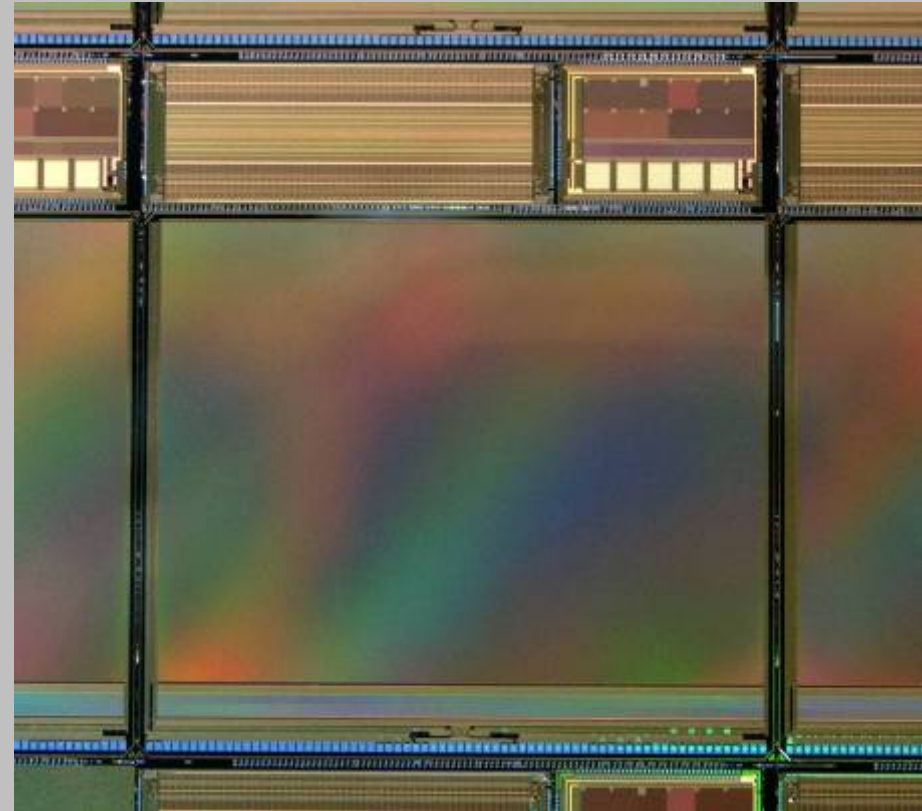


Photo ESA

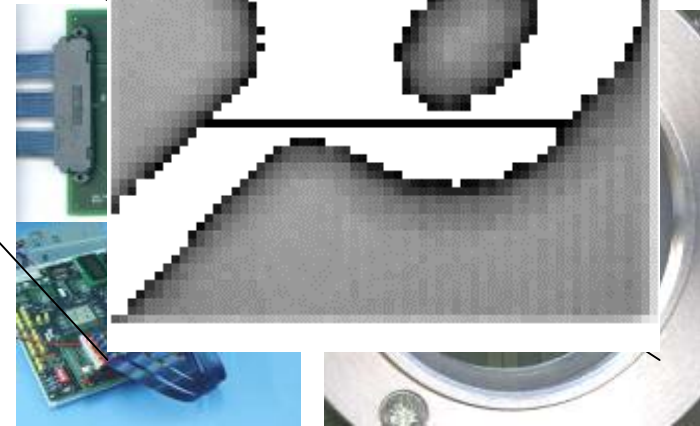
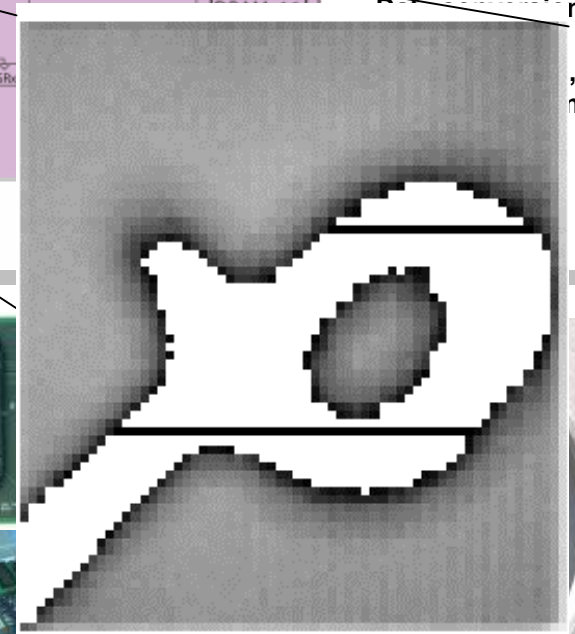
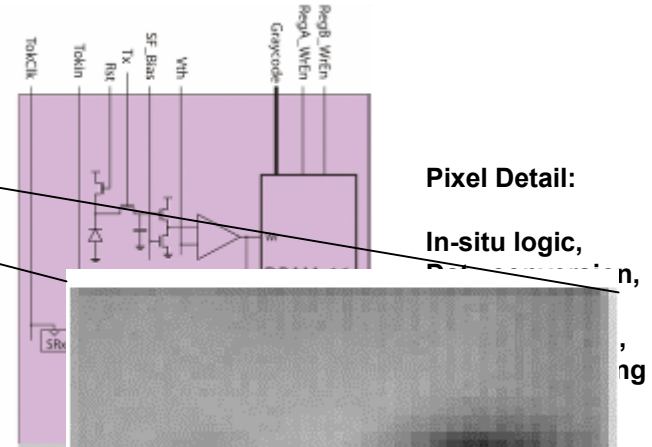
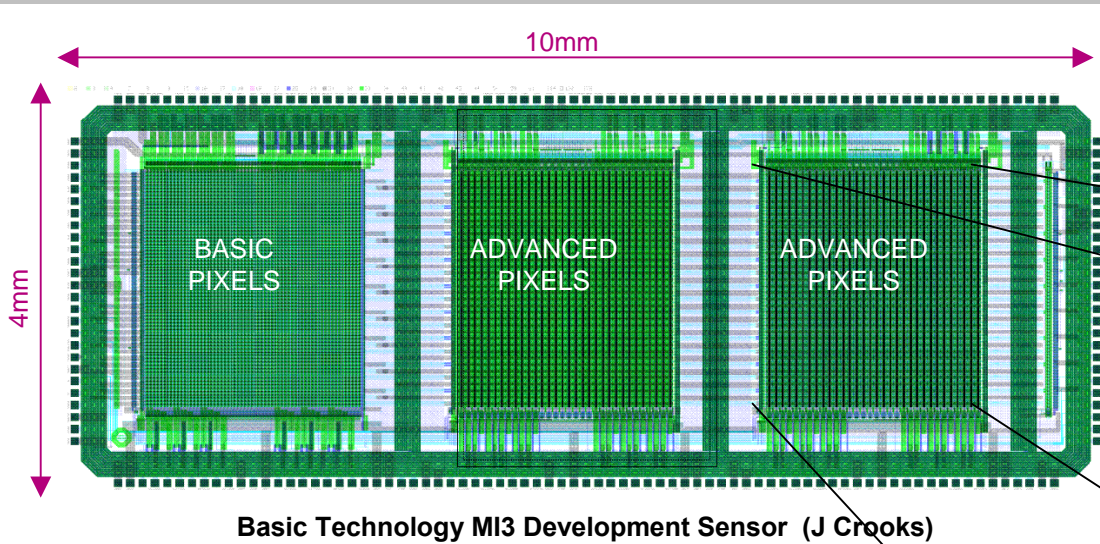


Various CCD Sensors



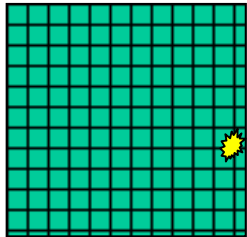
Large format CMOS devices

Mi3 Project: Advanced Pixels OPIC



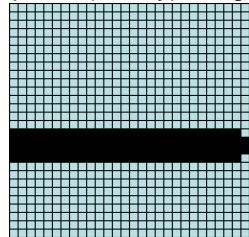
Test Rig

Photon Trace on Sensor



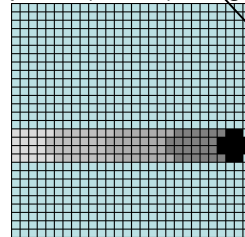
Single Frame
Time-of-flight 20us

Sparse (Binary) Image



Binary image of
pixels hit along
the way

Sparse (Timed) Image



Timing information
from hit pixels gives
80ns resolution

Moving Image Timed Capture

Pixel/sensor design

- Reduce noise
- Faster readout
- Data processing

Enhance spectral window

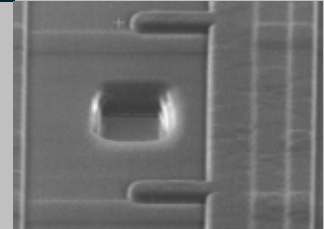
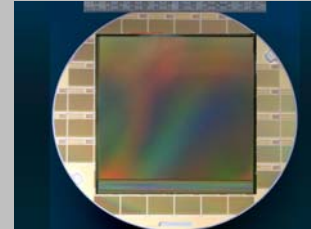
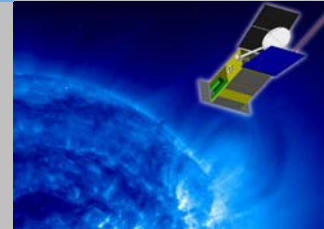
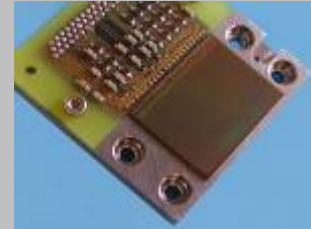
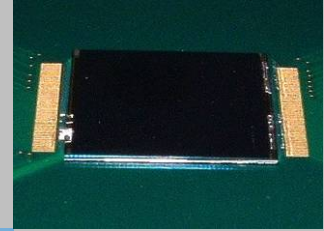
- Eliminate substrate for UV/low energy electrons
- Couple with scintillators of other materials for X and γ -rays

Radiation resistance

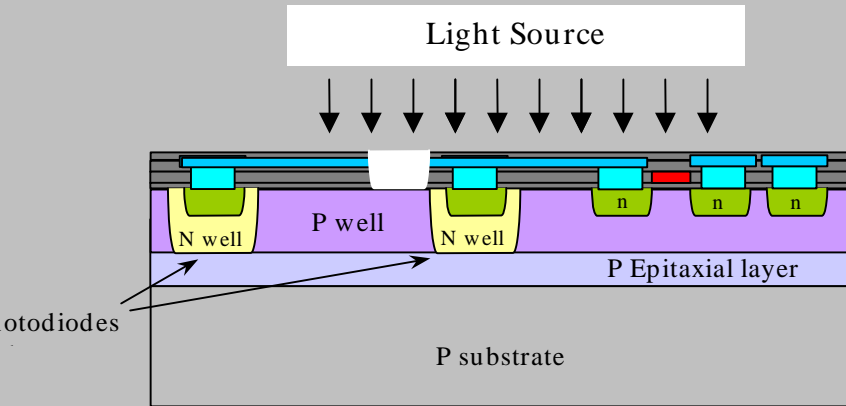
- OK for Linear Collider or in space
- what about the radiation levels found in LHC or other experiments?

Very large area sensors

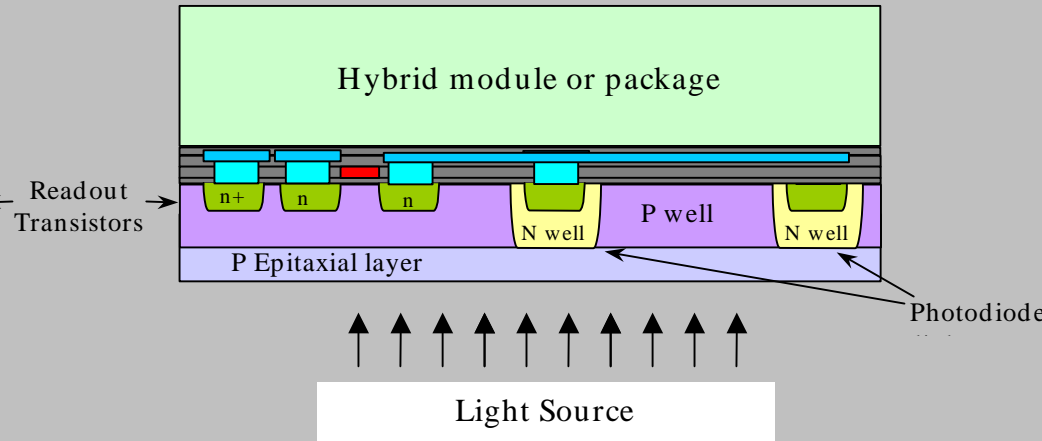
- Sensor larger than 2 cm side



Front & Back illumination

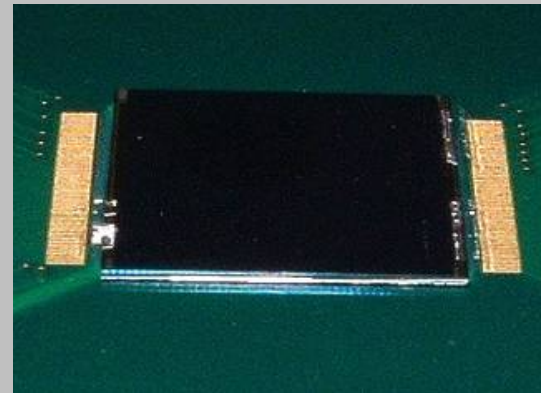


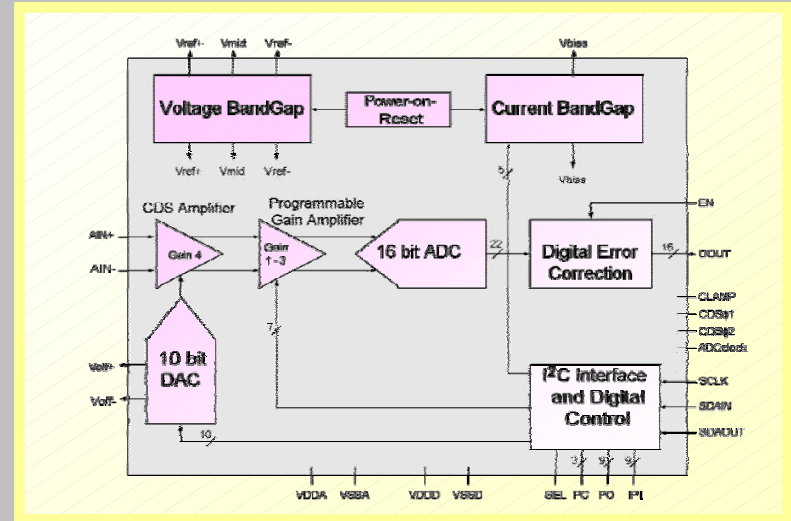
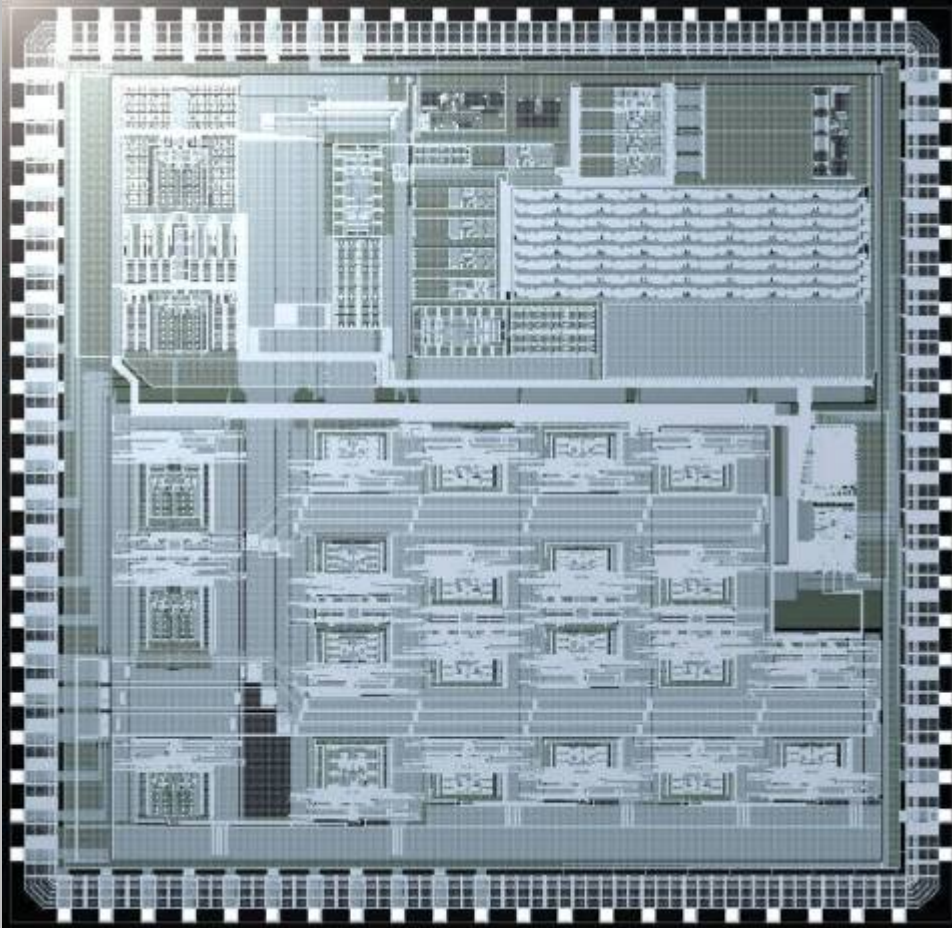
Front illuminated Etched MAPS



Back illuminated Thinned MAPS

**E2v collaboration:
Thinned CMOS Sensors**

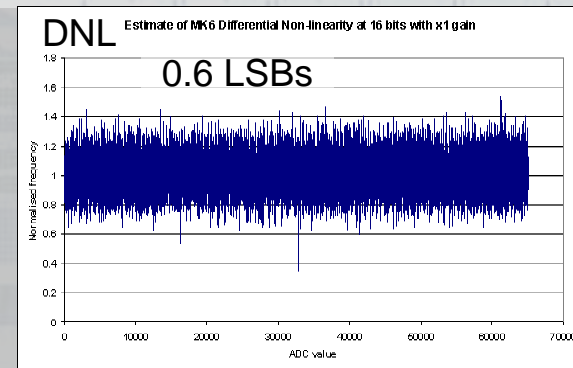
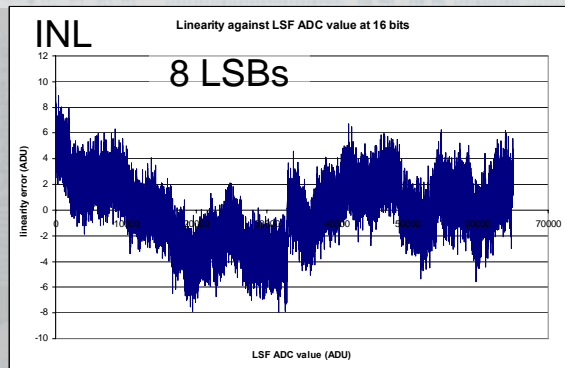
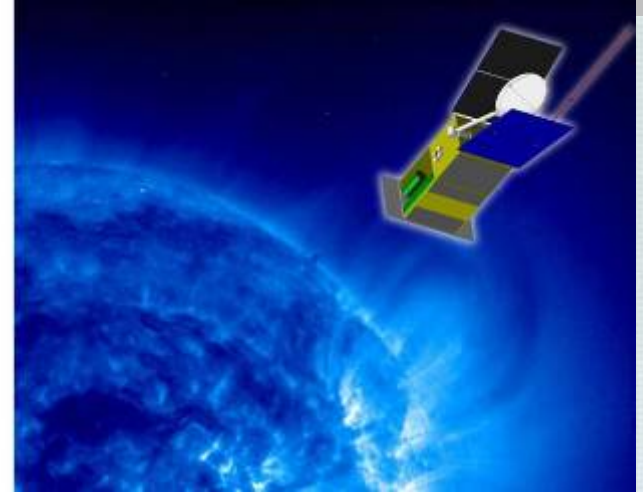




❑ CCD Image processing chip

- Correlated Double Sampling
- Programmable Offset / Gain
- On-Chip Reference
- Digital Interface

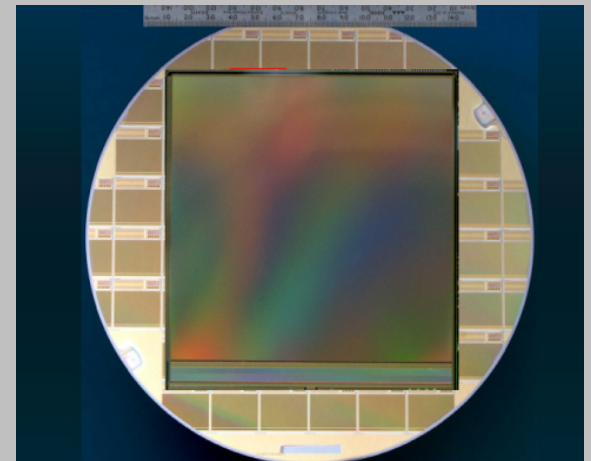
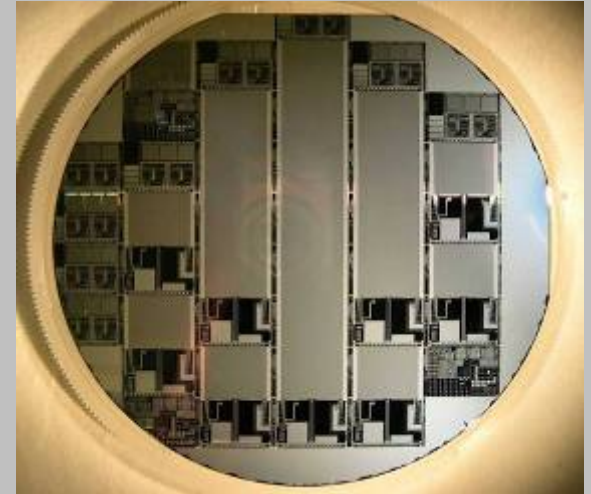
- ❑ A 16 bit pipelined ADC
- ❑ CCD signal processing chip
- ❑ Current Sample rate = 2.5MHz
- ❑ Fully differential architecture
- ❑ No missing or repeating codes



- Particle Physics:
 - Sensor Instrumentation
 - Microelectronics
 - DAQ Systems
- Space Science:
 - Instrument Systems
 - CMOS Sensors
 - Data conversion
- Future Trends



- Particle Physics (2 examples):
 - LHC Upgrades
 - More stringent ASIC requirements
 - More sophisticated data processing
 - LCFI
 - CCD and APS solutions in development
 - Very large area >100Mpixels
 - Drive for low mass in detector storage
- Space Science:
 - Performance
 - Lower power and noise
 - Enhanced spectral performance
 - Reliability
 - Rugged design
 - Radiation hardness

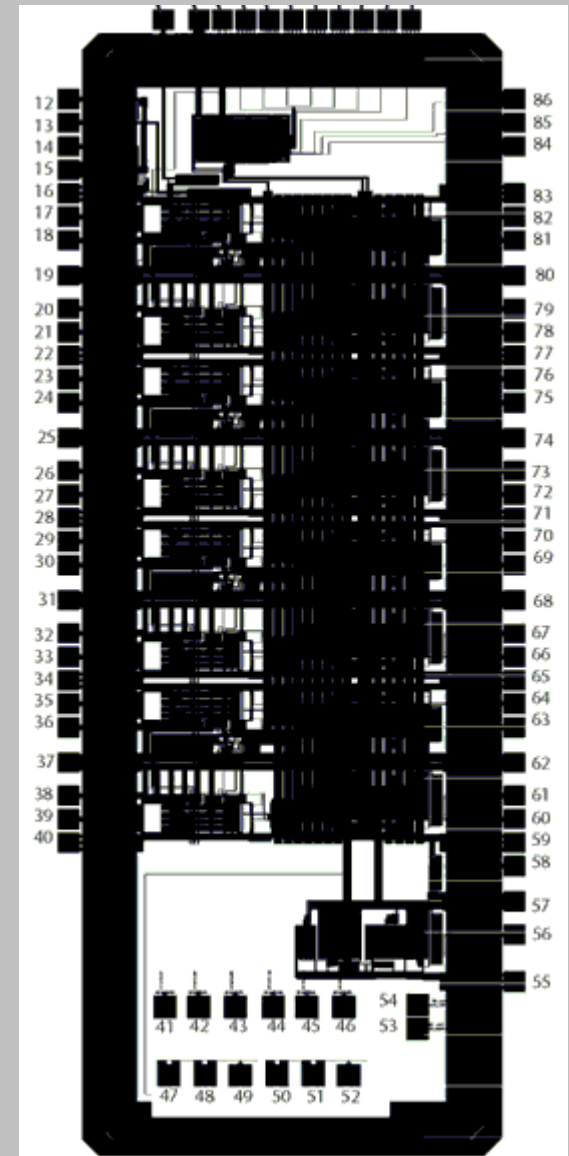


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 - Ideas for Nustar
 - Details for Aida
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- Parallel High and Low Gain
- Integrated input FET
- Ramp feedback system
- Low noise 0.35um technology

For combination with DAQ:

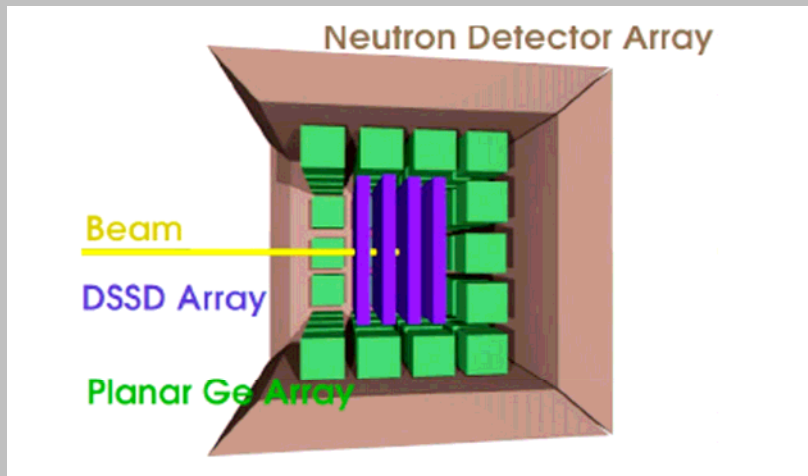
- future ADC
- timing etc.



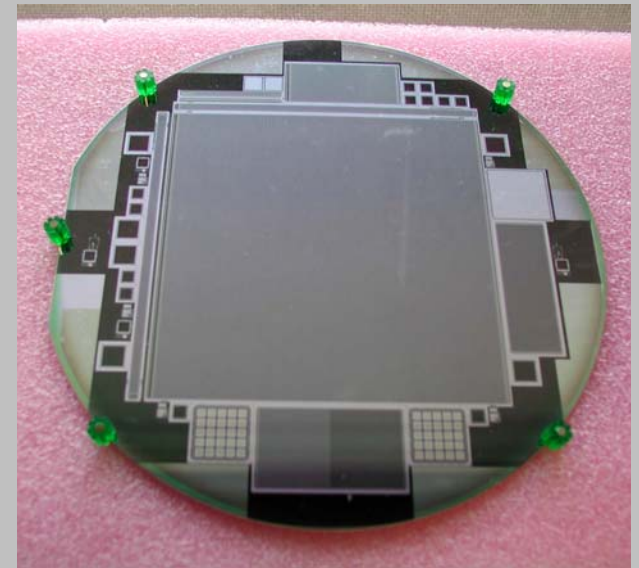
Examples currently identified:

- Fast recovery after implantation of ion in DSSD Si to measure decay in the same pixel.
- EXL CsI calorimeters covering energy range 300keV to 500MeV. 13k channels needed.
- EXL/R3B Si strip and SiLi detector ASIC. Normal Si processing chain of preamp, shaper, mux or ADC, timing. Add PSD too. Maybe 2 ASIC solution?

Concept and the detector

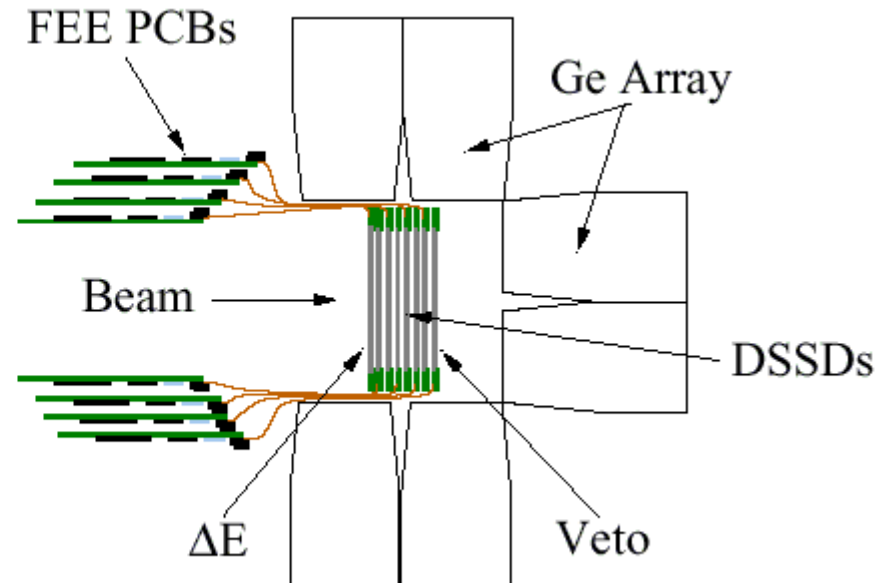
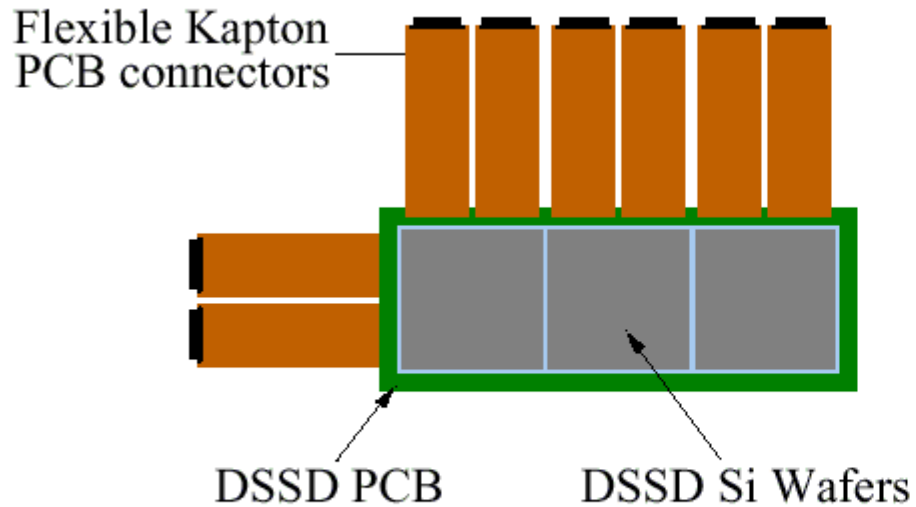


- Super FRS Low Energy Branch (LEB)
- Exotic nuclei – energies $\sim 50\text{-}150\text{MeV}/u$
- Implanted into multi-plane DSSD array
- **Implant - decay correlations**
- **Multi-GeV DSSD implantation events**
- Observe subsequent p , $2p$, α , β , γ , βp , βn ... decays
- Measure half lives, branching ratios, decay energies ...



- 6" wafer-10cm x 10cm area
- 1mm wafer thickness
- Integrated components
 - a.c. coupling
 - polysilicon bias resistors
 - ... important for ASICs
- Series strip bonding (3 together)

General Arrangement



DSSD Segmentation

We need to implant at high rates *and* to observe implant – decay correlations for decays with long half lives.

DSSD segmentation ensures average time between implants for given x,y quasi-pixel \gg decay half life to be observed.

- Implantation profile

$$\sigma_x \sim \sigma_y \sim 2\text{cm}$$

$$\sigma_z \sim 1\text{mm}$$

- Implantation rate (8cm x 24cm) \sim 10kHz, \sim kHz per isotope (say)
- Longest half life to be observed \sim seconds

Implies quasi-pixel dimensions \sim 0.5mm x 0.5mm

Segmentation also has instrumentation performance benefits

Instrumentation

Why use of Application Specific Integrated Circuit (ASIC) technology?

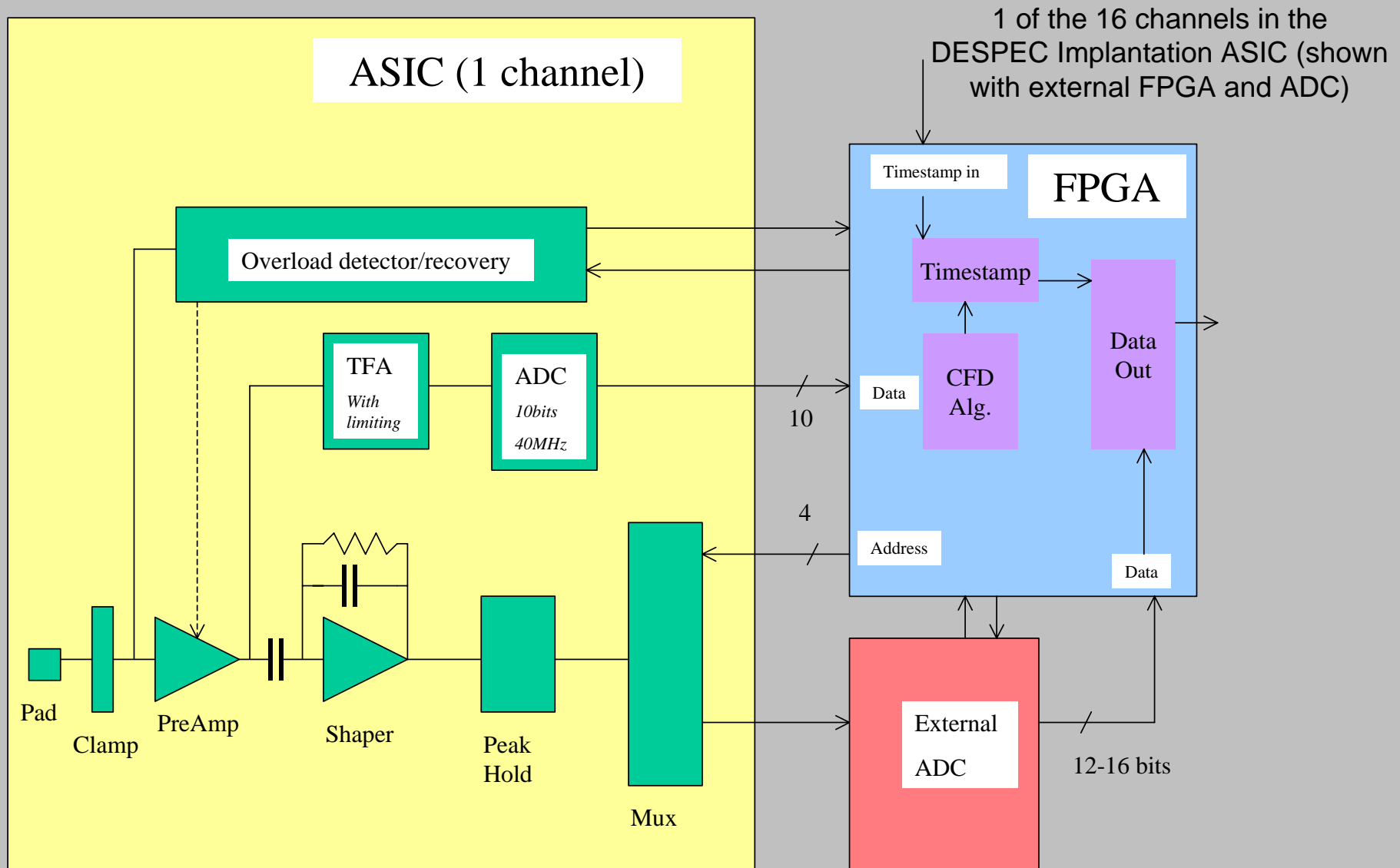
- Large number of channels required ($8 \times (128 + (3 \times 128)) = 4096$)
- Limited available space
- Cost

Outline ASIC Specification

- Selectable gain: low 20GeV FSR
 high 20MeV FSR
- Noise $\sigma \sim 5\text{keV rms.}$
- Selectable threshold: minimum $\sim 25\text{keV @ high gain (assume } 5\sigma)$
- Integral and differential non-linearity
- Autonomous overload recovery $\sim \mu\text{s}$
- Signal processing time $< 10\mu\text{s}$ (decay-decay correlations)
- Receive timestamp data
- Timing trigger for coincidences with other detector systems

DSSD segmentation reduces input loading of preamplifier and enables excellent noise performance.

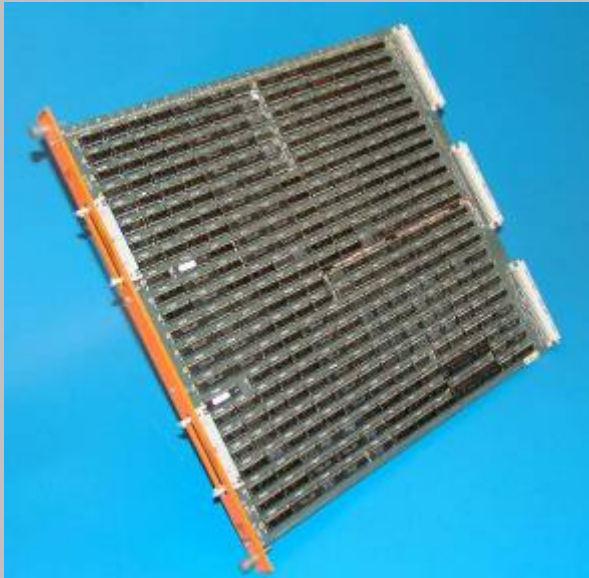
AIDA for DESPEC



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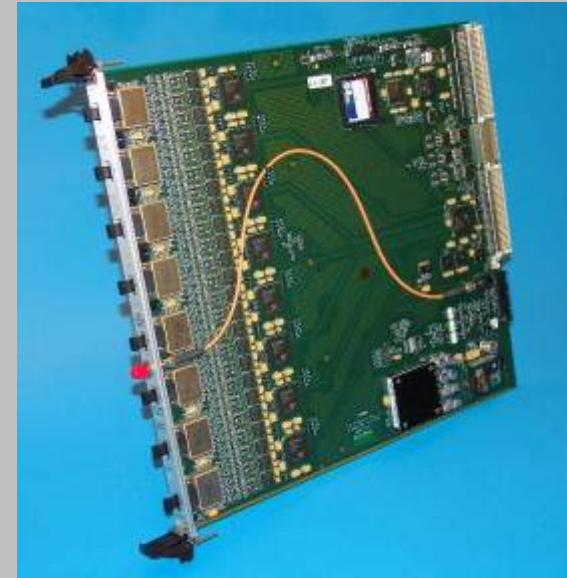
1980

- 300 MSI chips



1988

12 x 2K Gate FPGA
80 x 64Kx4 SRAM
10 PALs



2004

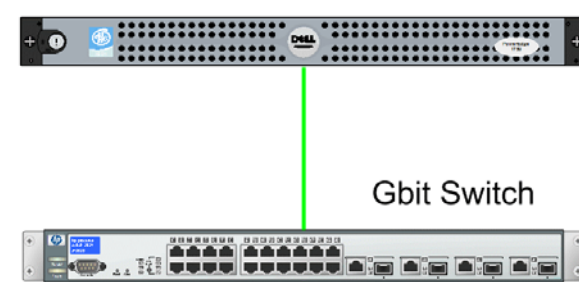
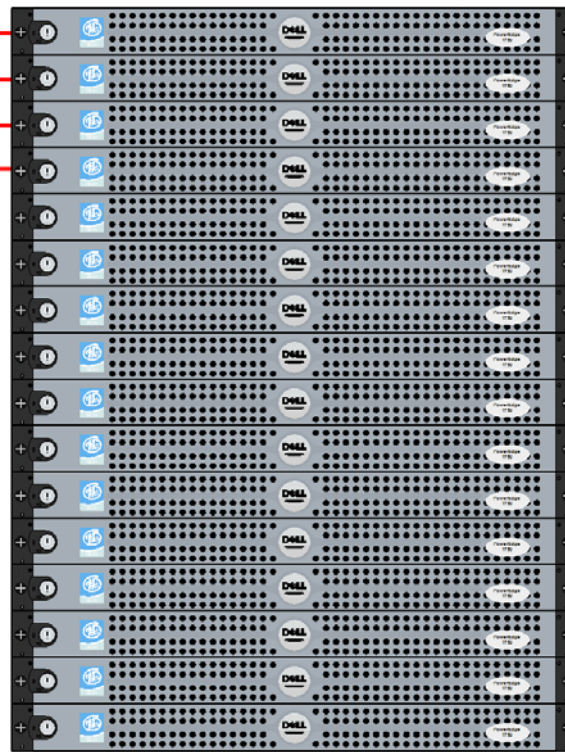
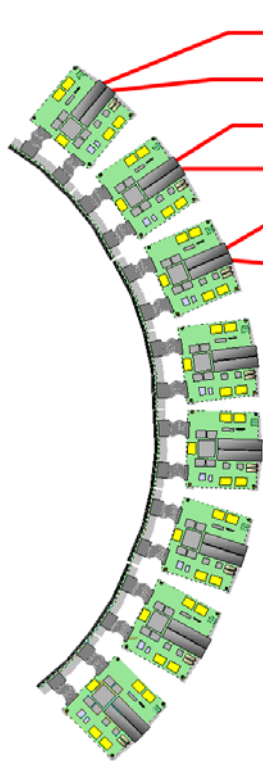
34 x FPGA
3 M Gate Virtex II
40 BGAs

Commercial Off Detector Electronics

Detector Array 32 x Gbit Optical Ethernet

Readout Processor Array

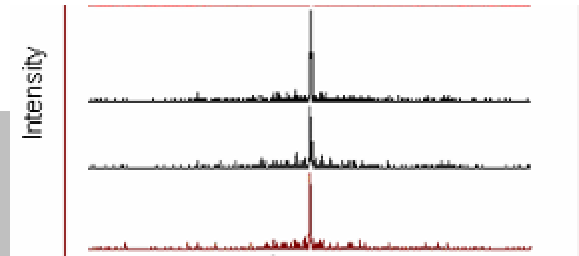
Master PC i/f to GDA

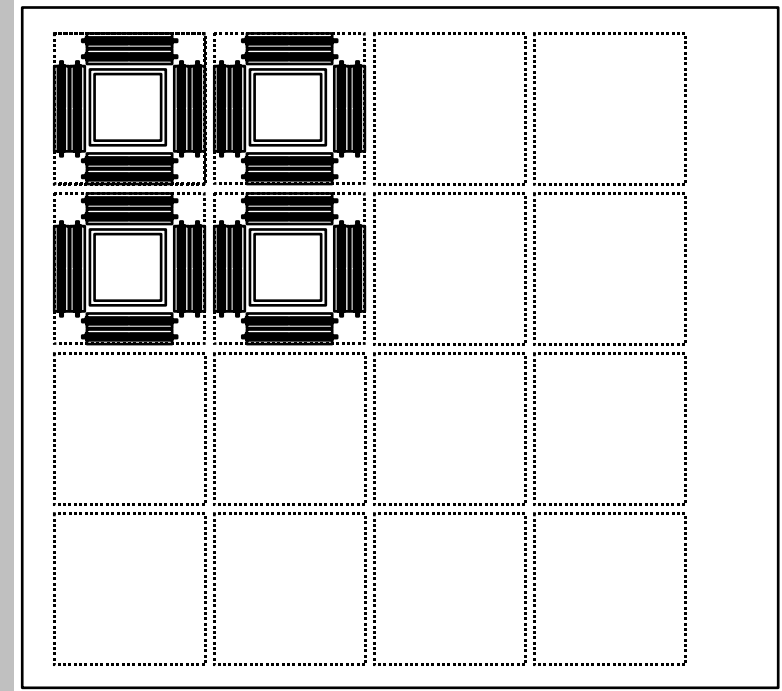
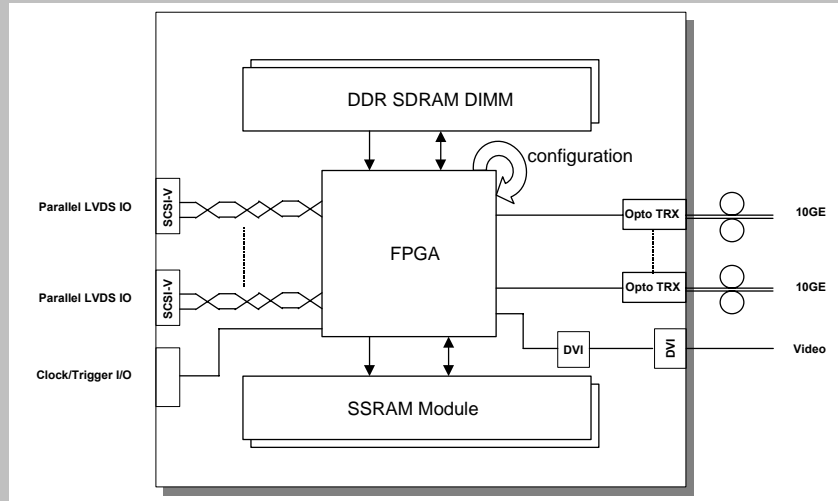


Backend Network
Gbit Ethernet Copper

10 Gbyte/s

2.5 Gbyte/s



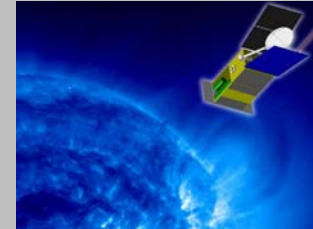
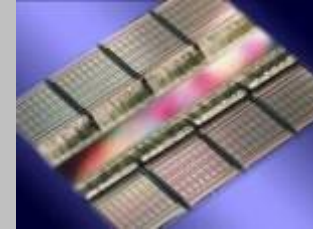
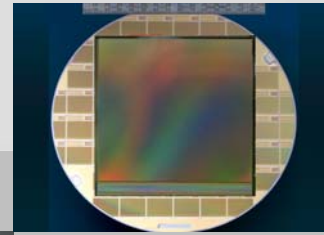


General observations:

- Future experiments always demand more data processing and reduction
- FPGAs offer a flexible multiprocessor offer massive compute potential
- Fibres permit very high data rates from instruments to processors

Instrument Technology:

- ASIC Design
 - Analogue, Low Power
 - Industrial technologies, CMOS based
- Imaging Devices
 - CCD and CMOS solutions
 - Complex designs, Novel architectures
- DAQ Systems
 - Large data processing capabilities
 - Multiprocessor fibre based systems
- New Projects for FAIR:
 - Aida DSSD Readout
 - EXL CsI calorimeters
 - EXL/R3B Si Strip and SiLi detector ASIC



And more technology..

